

Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

※ Except below description page

"Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan



FCAB22620L

Gate resistor installed Dual N-channel MOS FET
For lithium-ion secondary battery protection circuits

■ Features

- Source-source On-state Resistance : RSS(on) typ. = 2.4 mΩ (VGS = 3.8 V)
- CSP (Chip Size Package)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1)

■ Marking Symbol : W7

■ Packaging

Embossed type (Thermo-compression sealing) : 8 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

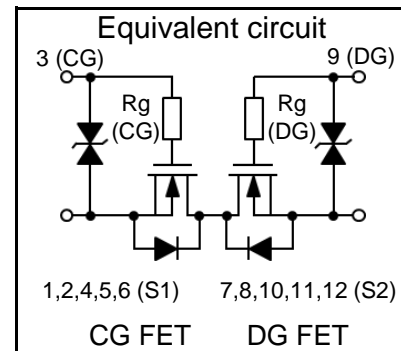
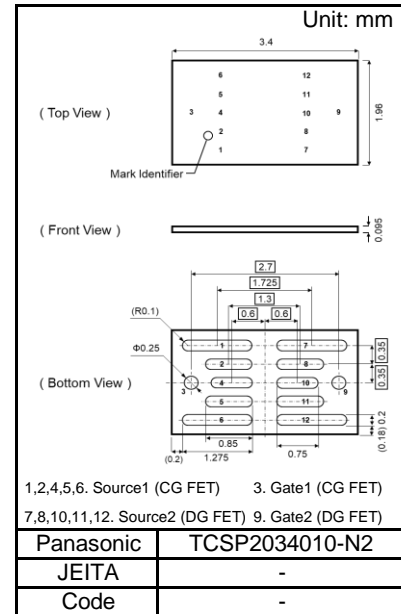
(MOSFET : CG FET, DG FET)

Parameter	Symbol	Rating	Unit
Source-source Voltage	VSS	23	V
Gate-source Voltage	VGS	±12	V
Source Current	DC	IS ^{*1}	13.8
		IS ^{*2}	24
		IS ^{*3}	33
	Pulsed ^{*4}	ISp	138
Total Power Dissipation	DC	PD ^{*1}	0.59
		PD ^{*2}	1.9
		PD ^{*3}	3.5
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

■ Thermal Characteristics Ta = 25 °C

Parameter	Symbol	Rating	Unit
Thermal Resistance (ch-a)	Rth ^{*1}	212	°C / W
	Rth ^{*2}	66	
	Rth ^{*3}	36	

- Note
- *1 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm).
FR4 board partially covered with copper pad (41 mm² area, 36 μm thickness).
 - *2 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm).
FR4 board fully covered with copper pad (604 mm² area, 36 μm thickness).
 - *3 Mounted on ceramic board (70 mm × 70 mm × t1.0 mm).
 - *4 Condition : t = 10 μs, Duty Cycle ≤ 1 %.





■ Electrical Characteristics Ta = 25 °C ± 3 °C
(MOSFET : CG FET, DG FET)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	23			V
Zero Gate Voltage Source Current	ISSS	VSS = 23 V, VGS = 0 V			1.0	μA
Gate-source Leakage Current	IGSS1	VGS = ±8 V, VSS = 0 V			±10	μA
	IGSS2	VGS = ±5 V, VSS = 0 V			±1.0	
Gate-source Threshold Voltage	Vth	IS = 1.15 mA, VSS = 10 V	0.35	0.9	1.4	V
Source-source On-state Resistance	RSS(on)1	IS = 6.9 A, VGS = 4.5 V	1.6	2.2	2.9	mΩ
	RSS(on)2	IS = 6.9 A, VGS = 3.8 V	1.7	2.4	3.1	
	RSS(on)3	IS = 6.9 A, VGS = 3.1 V	1.8	2.8	4.6	
	RSS(on)4	IS = 6.9 A, VGS = 2.5 V	3.0	5.0	9.8	
Body Diode Forward Voltage	VF(s-s)	IF = 6.9 A, VGS = 0 V		0.7	1.0	V
Input Capacitance ^{*1}	Ciss	VSS = 10 V, VGS = 0 V, f = 1 kHz		3500		pF
Output Capacitance ^{*1}	Coss			430		
Reverse Transfer Capacitance ^{*1}	Crss			340		
Total Gate Charge ^{*1}	Qg		VDD = 10 V		29	
Gate-source Charge ^{*1}	Qgs	VGS = 0 to 4 V		8		
Gate-drain Charge ^{*1}	Qgd	IS = 13.8 A		9		

(MOSFET : CG FET)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-on Delay Time ^{*1,2}	td(on)	VDD = 10 V, VCGS1 = 0 to 4 V		0.04		μs
Rise Time ^{*1,2}	tr	IS = 6.9 A		0.18		
Turn-off Delay Time ^{*1,2}	td(off)	VDD = 10 V, VCGS1 = 4 to 0 V		0.20		μs
Fall Time ^{*1,2}	tf	IS = 6.9 A		0.20		
Gate Resistance ^{*1}	Rg(CG)	f = 1 MHz	2	7	13	Ω

(MOSFET : DG FET)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-on Delay Time ^{*1,2}	td(on)	VDD = 10 V, VDGS2 = 0 to 4 V		1.2		μs
Rise Time ^{*1,2}	tr	IS = 6.9 A		2.6		
Turn-off Delay Time ^{*1,2}	td(off)	VDD = 10 V, VDGS2 = 4 to 0 V		5.2		μs
Fall Time ^{*1,2}	tf	IS = 6.9 A		4.1		
Gate Resistance ^{*1}	Rg(DG)	f = 1 MHz	400	700	1000	Ω

■ Electrostatic Discharge Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Class ^{*3}	Value	Unit
Human body model	HBM	C = 100 pF, R = 1.5 kΩ	H2	> 2k to ≤ 4k	V

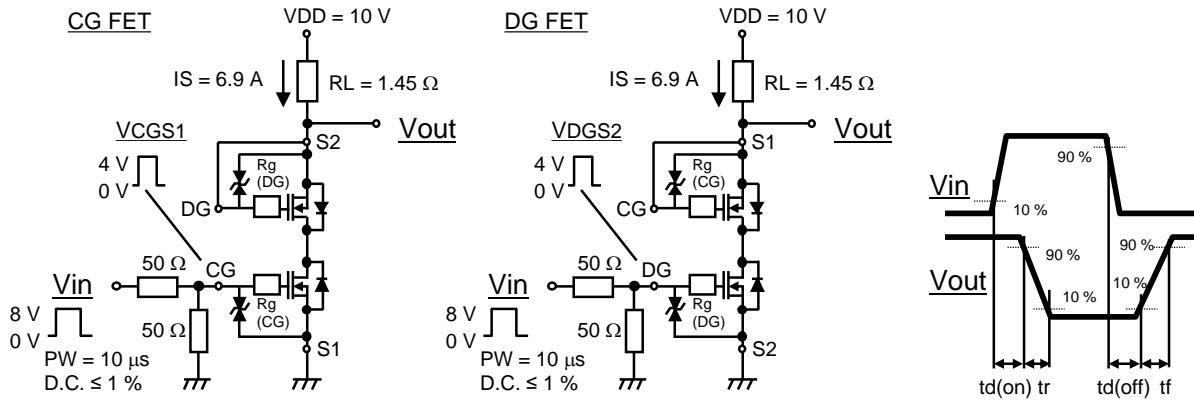
Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Guaranteed by design, not subject to production testing.

*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.

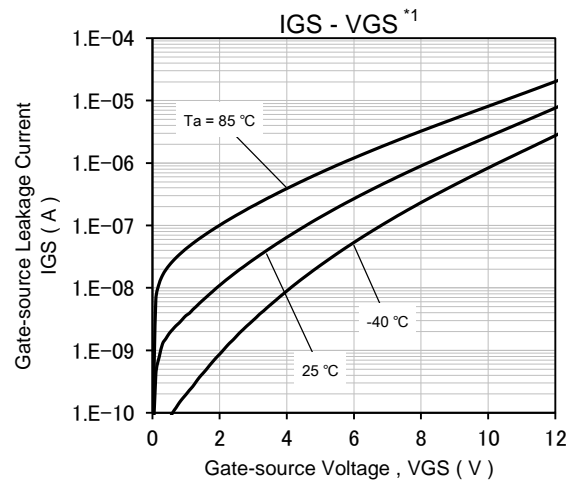
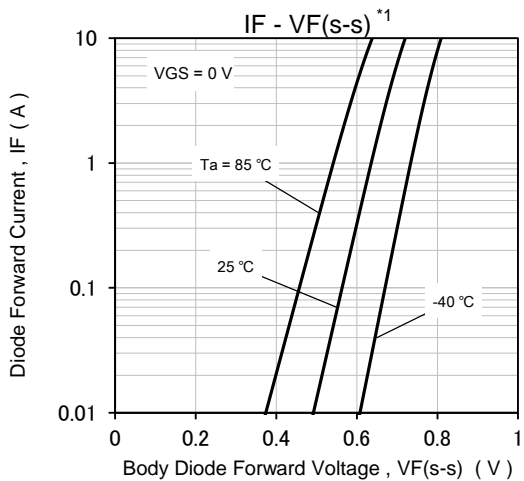
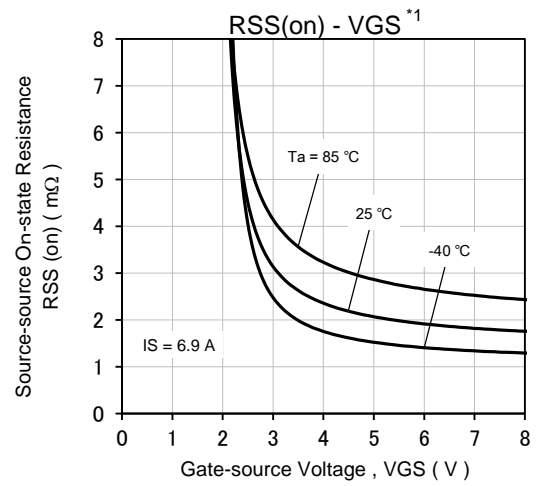
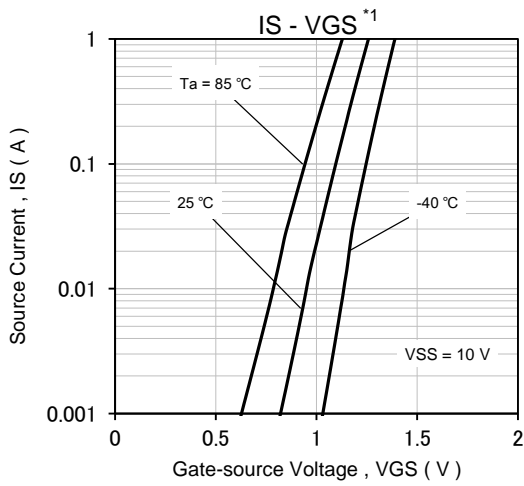
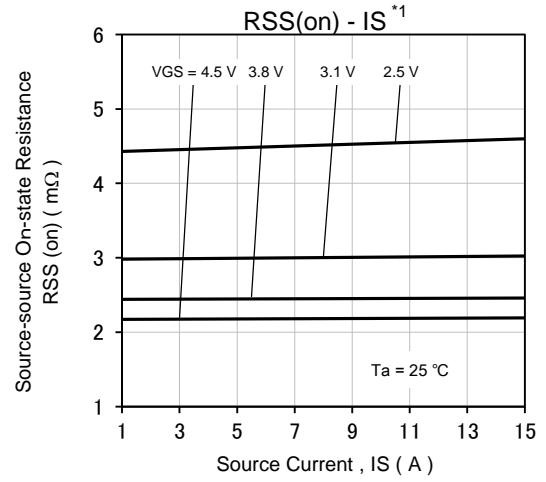
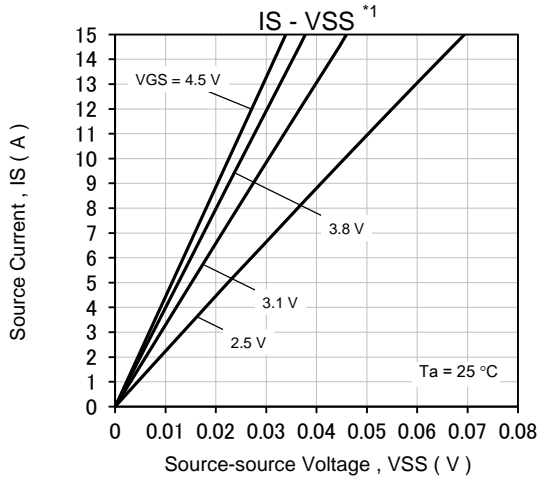
*3 AEC-Q101-001.

■ Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

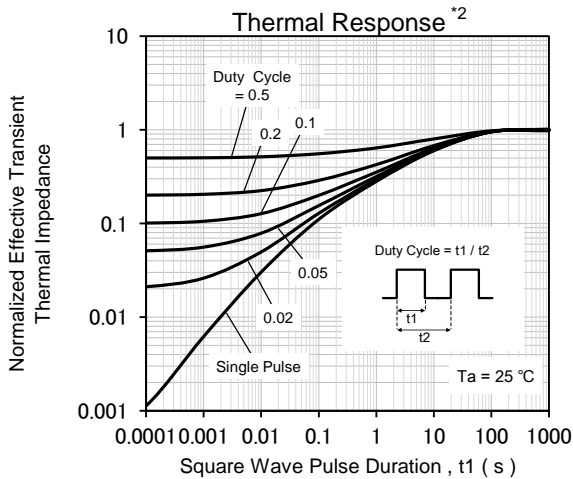
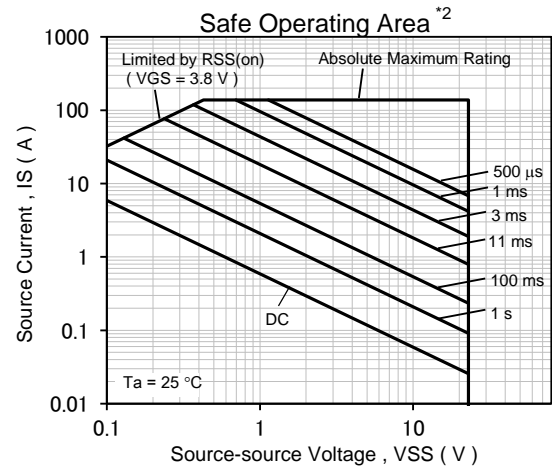
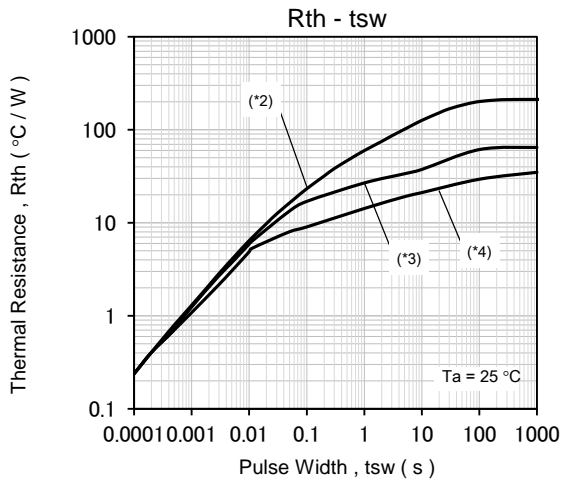
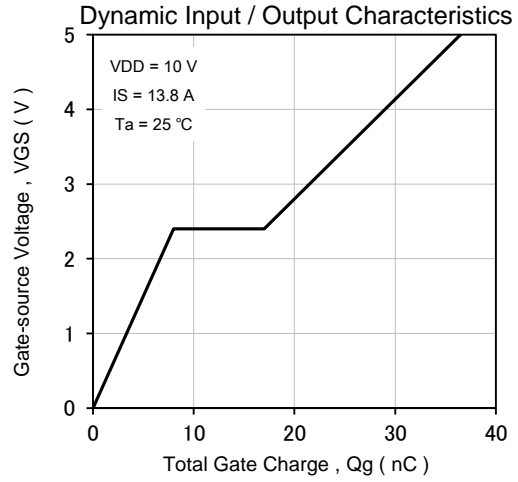
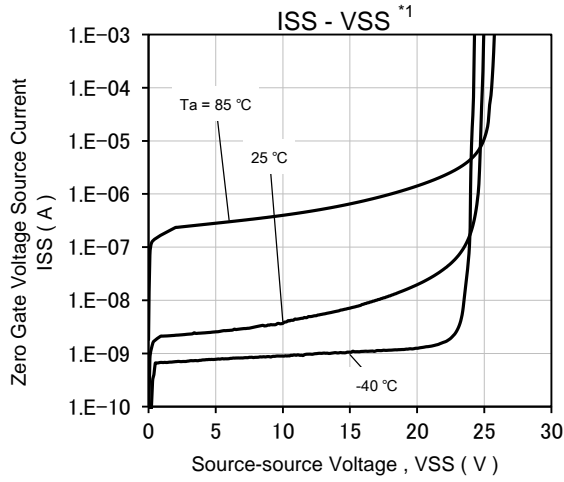




Technical Data (reference)



Technical Data (reference)

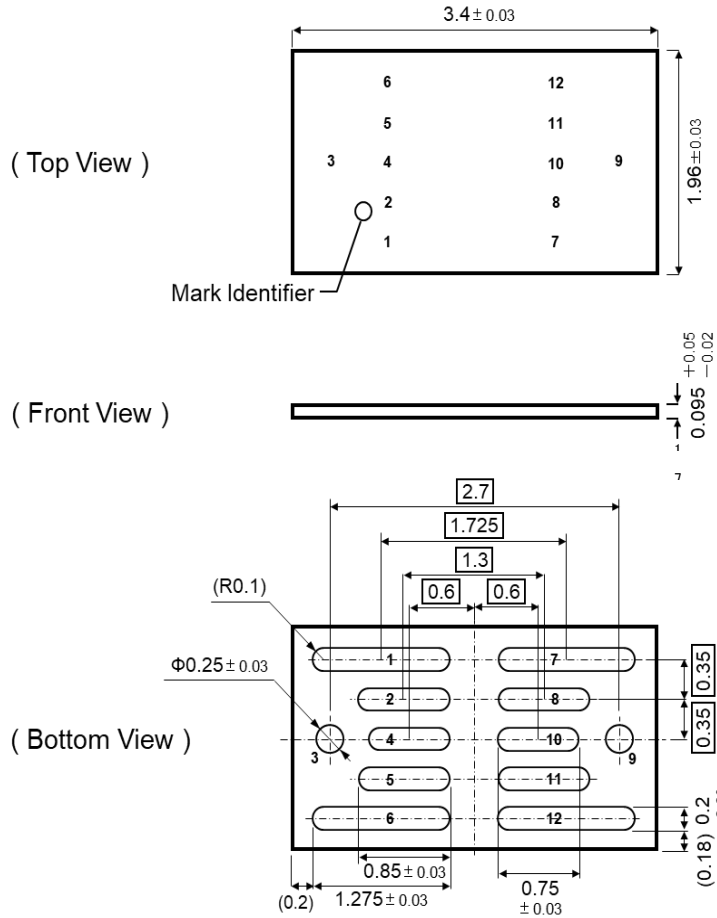


Note

- *1 Pulse measurement.
- *2 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm).
FR4 board partially covered with copper pad
(41 mm² area, 36 μm thickness).
- *3 Mounted on FR4 board (25.4 mm × 25.4 mm × t1.0 mm).
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(604 mm² area, 36 μm thickness).
- *4 Mounted on ceramic board (70 mm × 70 mm × t1.0 mm).

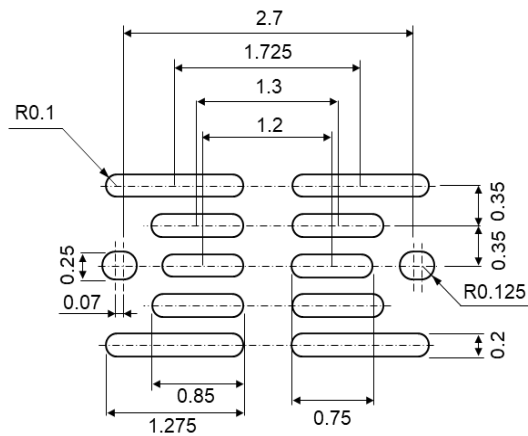
■ Outline

Unit: mm



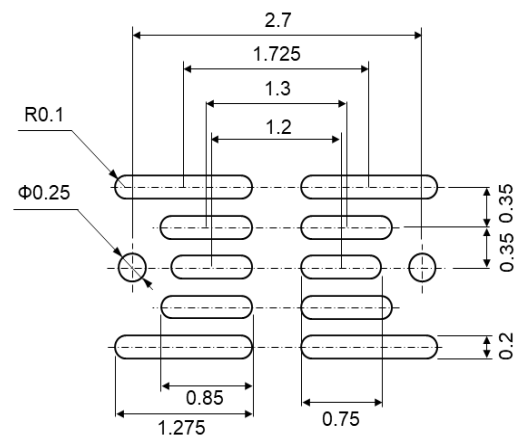
■ Land Pattern (reference)

Unit: mm



■ Stencil Pattern (reference)

Unit: mm



Datasheet Amendment History

Version	Status	Date	Change point(s)
-	Formal	2019.10.01	

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